Radial breathing mode of single-walled carbon nanotubes: Optical transition energies and chiral-index assignment

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We present a comprehensive study of the chiral-index assignment of carbon nanotubes in aqueous suspensions by resonant Raman scattering of the radial breathing mode. We determine the energies of the first optical transition in metallic tubes and of the second optical transition in semiconducting tubes for more than 50 chiral indices. The assignment is unique and does not depend on empirical parameters. The systematics of the so-called branches in the Kataura plot are discussed; many properties of the tubes are similar for members of the same branch. We show how the radial breathing modes observed in a single Raman spectrum can be easily assigned based on these systematics. In addition, empirical fits provide the energies and radial breathing modes for all metallic and semiconducting nanotubes with diameters between 0.6 and 1.5 nm. We discuss the relation between the frequency of the radial breathing mode and tube diameter. Finally, from the Raman intensities we obtain information on the electron-phonon coupling.

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I. INTRODUCTION

Single-walled carbon nanotubes are tiny cylinders made out of carbon.^{1–3} They have many unique, fascinating properties.¹ They are very strong and of extremely light weight, they are excellent conductors of heat, and transport electrons ballistically. The properties of carbon nanotubes depend strongly on their microscopic structure, which is defined by the chiral index (n_1, n_2) . The best known example for this is that 2/3 of all possible nanotubes are semiconductors and 1/3 are metals.¹

Many applications of carbon nanotubes need one particular type of tube, e.g., semiconducting tubes for transistors. Also, in fundamental studies we want to know which nanotube is probed experimentally. The growth of carbon nanotubes with a predefined microscopic structure remains a major challenge. Therefore the experimental determination of the chiral index is a current focus of carbon nanotube research.⁴⁻⁹ In principle, the chiral index of an individual tube can be determined by direct imaging techniques like scanning tunneling microscopy. However, the experimental error in the measurement of diameter and chiral angle leads to uncertainties in the assignment of the chiral index. For example, the (13,1) tube with diameter d=1.06 nm and chiral angle $\theta = 3.7^{\circ}$ is geometrically close to the (14,1) tube $[d=1.14 \text{ nm and } \theta=3.4^\circ]$, but the (13,1) tube is metallic and the (14,1) tube is semiconducting.

Optical spectroscopy like photoluminescence and Raman scattering uses properties that are different for each chiral index, i.e., electronic energies and phonon frequencies, to assign n_1 and n_2 . These methods are suitable also for macroscopic amounts of nanotubes. At least two pieces of information are needed for an assignment, e.g., the combination of optical absorption and emission energies in photoluminescence and the phonon frequency plus one optical transition energy in Raman scattering. The assignment is then based on pattern recognition between experimental and theoretical

data.^{4,7,8} Because of the systematics in the data of many nanotubes used for pattern recognition, the assignment is stable against variations from small experimental errors.

Optical methods are nondestructive and carry a large amount of information besides the information needed for the assignment itself. This has been demonstrated over the past three years by absorption and emission spectroscopy, time-resolved optical spectroscopy, and two-photon absorption.^{4–16} Because of the photoluminescence-based assignment suggested by Bachilo *et al.*,⁴ the tubes selected in the optical studies were known. In this way, the electronic states, optical selection rules, carrier dynamics, etc., of semiconducting tubes were studied as a function of the tube diameter and chiral angle.

The advantage of Raman scattering over photoluminescence is that it can identify both metallic and semiconducting nanotubes.^{7,8,17–19} Also, in semiconducting nanotubes Raman spectroscopy can be performed in resonance with the second optical transition, which is in the visible energy range. Thus no infrared-sensitive spectrometers and detectors are needed. Finally, the Raman signal is more robust with respect to the environment of the nanotube. Photoluminescence, for example, is quenched in nanotube bundles by the presence of metallic tubes,¹⁴ whereas the Raman signal is still present. Raman spectroscopy holds promise of identifying nanotubes in different environments with standard equipment.

The Raman experiments for an assignment of n_1 and n_2 reported so far were very laborious and required tunable lasers over wide energy ranges.^{7,8,17,18} Now a straightforward procedure to perform an assignment using one or two Raman spectra is needed. Also, we need to know by how much the environment of the tube affects the nanotube phonons and optical transition energies, because these two features are essential for an assignment based on Raman scattering. Early studies on the environment related effects concentrated on bundled tubes versus isolated surfactant-coated nanotubes in solution.^{8,20} The interaction between the tubes in a bundle

was found to shift the optical transition energies to the red as predicted by *ab initio* calculations by our group.²¹ In both experimental studies sodium dodecyl sulfate (SDS) was used as the surfactant for the debundled nanotubes. It will be important to know whether small changes in the tube's environment, e.g., a different surfactant, affect the phonon frequencies and optical transition energies.

Here we present a full analysis of the (n_1, n_2) assignment from resonant Raman scattering of the radial breathing mode (RBM). We discuss the systematics of the so-called branches in the Kataura plot, where the optical transition energies are given as a function of the RBM frequency. The experimental data are extended by empirical fits to a larger range of tube diameters. We show that our assignment is unique without additional parameters. From this assignment, the coefficients c_1 and c_2 for the relation between diameter and RBM frequency are determined. By analyzing the intensity of the Raman signal, we observe systematic dependences of the Raman cross section on the chiral angle and on the nanotube family index $\nu = \pm 1$. Our results confirm recent *ab initio* calculations of the matrix elements of the electron-phonon interaction for the RBM.²² Changing the nanotube environment by using a different surfactant leads to variations in the RBM intensity and to small shifts in the optical transition energies. In metallic tubes we also observed small shifts in the RBM frequencies. These changes do not affect our pattern-based Raman assignment, but they show that the RBM frequency alone-discarding the information about the Raman excitation energy-will never be sufficient to identify the chirality of a tube. Finally, we explain the procedure for using our experimental and empirical data to assign the RBM peaks observed in a single Raman spectrum.

This paper is organized as follows: in Sec. II we give a brief overview over the radial breathing mode and previous attempts for (n_1, n_2) assignment based merely on the RBM frequency. The experimental methods are presented in Sec. III. In Sec. IV we explain the concept of resonant Raman scattering to determine the optical transition energies. The (n_1, n_2) assignment is discussed in Sec. V. The experimental data are compiled and extended to arbitrary nanotubes using empirical functions in Sec. VI. In Sec. VII we derive the constants c_1 and c_2 of the relation between RBM frequency and inverse diameter and discuss deviations from a linear behavior. In Sec. VIII the RBM intensity is analyzed as a function of the chiral angle. In Sec. IX we discuss surfactantinduced changes of the RBM spectra and transition energies. Finally, we give an instruction on how to assign the RBM peaks in a Raman spectrum to (n_1, n_2) in Sec. X.

II. RADIAL BREATHING MODE

The radial breathing mode is the characteristic phonon mode of single-walled carbon nanotubes.¹ All atoms of the tube vibrate in-phase in the radial direction; see Fig. 1. A small nonradial component of the atomic displacement arises from mixing with the fully symmetric high-energy phonons.^{22–24} If the nanotube is approximated by a homogeneous cylinder, the frequency of the radial vibration is linear with the inverse tube diameter 1/d,¹



FIG. 1. (Color online) Radial breathing mode of an (8,4) nanotube. The arrows show the phonon eigenvector. The RBM leads to a periodic increase and decrease of the tube diameter as shown by the wire model of the tube.

$$\omega_{\text{RBM}} = \frac{c_1}{d} + c_2. \tag{1}$$

The offset c_2 was originally introduced to account for additional external forces, e.g., from interactions with a substrate or neighboring tubes in a bundle.^{25,26} On the other hand, changes in the environment of the tubes probed so far lead to rather small changes in the RBM frequencies.^{8,20} Therefore c_2 should be regarded more as a fitting parameter. The geometrical diameter *d* is given by

$$d = a_0 \sqrt{n_1^2 + n_1 n_2 + n_2^2} / \pi, \qquad (2)$$

where $a_0=2.461$ Å is the in-plane lattice constant of graphite. Kürti *et al.*²⁴ showed by *ab initio* calculations that deviations from Eq. (1) occur for small-diameter tubes, which additionally depend on the chiral angle. These deviations are caused by first the small nonradial component of the vibration. Second, the fully relaxed atomic structure of the tube has a slightly different diameter than the ideal geometrical diameter from Eq. (2).²⁴

The ω_{RBM} -diameter relation [Eq. (1)] is often used to determine the tube diameters and the diameter distribution in a nanotube sample from Raman scattering. Comparing the diameter and Eq. (2), the chiral indices are extracted, giving an assignment of RBM frequencies to particular (n_1, n_2) nanotubes.²⁷⁻²⁹ This method requires the knowledge of the coefficients c_1 and c_2 . However, experimental and theoretical values of c_1 reported in the literature vary between 220 and 260 cm⁻¹ nm; c_2 varies between 0 and 20 cm⁻¹, see, for instance, Refs. 27 and 30-32. For example, with $c_1 = 248 \text{ cm}^{-1} \text{ nm}$ and $c_2 = 0 \text{ cm}^{-1}$, the observed RBM at 164 cm⁻¹ was assigned to the (11,11) tube.²⁷ But if we choose a value obtained from ab initio calculations instead, $c_1 = 223 \text{ cm}^{-1}$, a different peak (148 cm⁻¹) is assigned to the (11,11) tube. Thus the assignment is very sensitive to the precise values of c_1 and c_2 , and a particular RBM peak will be correlated with different (n_1, n_2) depending on the variation of c_1 and c_2 . An assignment based on ω_{RBM} alone is in most cases not reliable, in particular for larger-diameter tubes with close-by RBM frequencies. It cannot be improved by higher accuracy in the experiment. Therefore a second piece of information must be taken into account, as we show in Sec. V.

III. EXPERIMENTAL METHODS

Raman experiments were performed on HiPCO-produced carbon nanotubes,³³ suspended in D₂O and wrapped by a surfactant (SDS, sodium dodecyl sulfate, and SDBS, sodium dodecylbenzene sulfonate).⁵ The samples were excited by tunable Ti:sapphire and dye lasers and by an ArKr laser with powers of ≈ 15 mW focused into the nanotube solution. The scattered light was collected in backscattering geometry, dispersed by a Dilor XY800 triple monochromator and detected by a charge-coupled device. The spectra were calibrated with a neon lamp. We normalized the Raman intensity with respect to the nonresonant Raman signal of CaF₂ and BaF₂ and to the laser power and integration time.

IV. RESONANT RAMAN SCATTERING

In Raman scattering, the signal intensity increases strongly when the excitation energy approaches an allowed optical transition.^{19,34} If the incoming or scattered light match the transition energy, this is called a resonance, and the intensity is at maximum. Recording the Raman intensity as a function of laser energy, we can determine the transition energies E_{ii} in carbon nanotubes. The method is suitable for both semiconducting and metallic nanotubes, in contrast to photoluminescence, which probes only semiconducting tubes. By Raman spectroscopy we can directly probe the optical transition probability for E_{ii} , given the electronphonon coupling is known. In contrast to photoluminescence, the strength of the signal is not additionally determined by the efficiency of absorption into other electronic bands and of relaxation into dark and luminescent states.^{35,36}

In Fig. 2(a) we show the RBM spectra at different excitation energies. We see groups of several close-by peaks having their maximum strength one after the other, starting from the highest frequency and resembling a *laola* wave.³⁷ Each peak will be assigned to a different nanotube chirality (n_1, n_2) ; see Sec. V. In Fig. 2(b) we show as an example the resonance profiles of four peaks belonging to the same group. The peak with the largest RBM frequency has its resonance maximum at the lowest energy. The resonance energy increases as the RBM frequency decreases, and only for the last RBM peak, the resonance energy decreases slightly again. From the assignment (Sec. V) we find that such groups of RBM peaks form so-called branches in the Kataura plot. Each tube in a branch is related to its neighbor by $(n'_1, n'_1) = (n_1 - 1, n_2 + 2).^{7,19}$

The Raman resonance profile is a superposition of an incoming and an outgoing resonance and can be described by³⁴

$$I(E_l) = \left(\frac{\mathcal{M}c}{\hbar\omega_{\text{RBM}}}\right)^2 \left|\frac{1}{(E_l - E_{ii} - i\gamma/2)} - \frac{1}{(E_l - \hbar\omega_{\text{RBM}} - E_{ii} - i\gamma/2)}\right|^2, \quad (3)$$

where E_l is the laser energy, E_{ii} the energy of the allowed



FIG. 2. (Color online) (a) RBM spectra of carbon nanotubes at different excitation energies. The spectra are vertically offset for clarity. From top to bottom the laser energy increases between 1.51 and 1.75 eV. Each peak arises from a different (n_1, n_2) nanotube. (b) Resonance profiles for the peaks marked in (a) by vertical lines. The dots are experimental data; the lines are fits according to Eq. (3).

optical transition, and γ the lifetime broadening of the intermediate electronic states. \mathcal{M} contains all matrix elements and *c* summarizes all remaining factors. An incoming resonance occurs when $E_l = E_{ii}$, and an outgoing resonance when $E_l = E_{ii} + \hbar \omega_{\text{RBM}}$. If the incoming and outgoing resonances are not resolved in the resonance profile, the resonance maximum is at $\approx E_{ii} + 0.5 \hbar \omega_{\text{RBM}}$.

Equation (3) describes Raman scattering for a single resonant intermediate state E_{ii} . This corresponds to an excitonic transition, where the wave vector of the optically created exciton $Q = k_e + k_h$ is fixed by the momentum of the incoming photon $k_i = Q \approx 0$ (k_e and k_h are the wave vector of the electron and hole, respectively). Excitons have been shown to dominate optical transitions at room temperature in single-walled carbon nanotubes.^{15,16} We therefore use resonant Raman scattering by excitons to describe our spectra.

We now briefly comment on the modifications of the resonant Raman cross section [Eq. (3)] when considering bandto-band transitions, i.e., uncorrelated electrons and holes. A full discussion can be found in a review article by Thomsen and Reich.¹⁹ For band-to-band transitions, E_{ii} is identified with the band gap of the resonant state instead of the Q=0 exciton energy. Additionally, in Eq. (3) the square root of the incoming and outgoing resonance term has to be taken, see also Bussi et al.³⁸ Despite these differences in the Raman matrix elements, the Raman profiles (squared matrix element) obtained for excitonic and band-to-band transitions are identical for all practical purposes. Only the line shapes are slightly different, but they are indistinguishable in practice. Depending on the exact value of the electronic lifetime parameter, the experimental linewidth can also be different for band-to-band compared to excitonic resonances when using the same γ in both calculations. Since γ is not known independently, a Raman resonance profile cannot be used to discriminate between the two transition models; see Ref. 19. We stress that under no circumstances is a resonant Raman profile with the line shape of a square-root singularity (as suggested in Ref. 27) expected.³⁸

Since excitons were found to dominate the optical spectra of semiconducting nanotubes by two-photon spectroscopy,^{15,16} Eq. (3) is certainly correct for semiconducting tubes. For metallic tubes, binding energies ≈ 50 meV were predicted by first-principles calculations.³⁹ This binding energy is still more than twice the thermal energy at room temperature. It thus seems that metallic nanotubes also have excitonic resonances, because the Coulomb interaction is only screened along the nanotube axis. We therefore use Eq. (3) to fit the resonance Raman profiles of both semiconducting and metallic tubes. We stress that the *experimental* optical transition energies are not affected by the choice of the model.¹⁹ E_{ii} are simply experimental values that need to be interpreted by a theoretical model.³⁶

By fitting the resonance profiles in Fig. 2(b) with Eq. (3), we obtain for each RBM peak the corresponding transition energy E_{ii} . For the broadening γ we obtained $\gamma \sim 0.06$ eV for most transitions. The experimental data presented in Refs. 8 and 9 from SDS-wrapped HiPCO tubes agree with ours to within experimental error. In Tables I and II we summarize all measured RBM frequencies and optical transition energies E_{ii} .

V. (n_1, n_2) ASSIGNMENT OF RBM FREQUENCIES AND TRANSITION ENERGIES

Having determined the pairs of RBM frequencies and transition energies ($\omega_{\text{RBM}}, E_{ii}$), we show in this section how we assign them to particular tube chiralities (n_1, n_2) .⁷ The assignment is based on characteristic patterns in the experimental and theoretical data. We do not require a *quantitative* agreement between theory and experiment. Neither do we use any calculated transition energies or RBM frequencies nor the luminescence-based assignment suggested by Bachilo *et al.*⁴

The RBM frequency ω_{RBM} is proportional to the inverse diameter, $\omega_{\text{RBM}} \propto 1/d$ [Eq. (1)]. We therefore obtain an experimental Kataura plot by plotting E_{ii} as a function of $1/\omega_{\text{RBM}}$; see Fig. 3 (large open and closed circles).^{7,40} We do not use any additional assumptions; in particular, the values of the coefficients c_1 and c_2 in Eq. (1) are unknown. The assignment is found by comparing the experimental Kataura plot with a theoretical one (small gray circles in Fig. 3). The theoretical transition energies are calculated from a thirdnearest-neighbor tight-binding approximation, fit to densityfunctional-theory calculations (DFT).⁴¹ To make both Kataura plots match we have to shift and stretch the axes of one Kataura plot with respect to the other.

On the energy axis, the necessary shift and stretching reflects the uncertainties in the calculation of the optical transitions. The tight-binding calculation does not account for curvature effects, electron-electron, and electron-hole interaction. In particular, excitonic effects^{36,39,42–44} have been shown to dominate the optical transitions with binding energies ~400 meV.^{15,16} Along the diameter axis, stretching of the Kataura plot corresponds to adjusting the unknown coefficient c_1 in Eq. (1); the shift leads to the offset c_2 .

In the following we explain the procedure and the criterion for a correct assignment in more detail. The transition energies as a function of tube diameter follow roughly a 1/d dependence (solid lines in Fig. 3). Chirality-dependent deviations from this behavior result in "V"-shaped branches (dashed lines in Fig. 3). The tubes with largest chiral angle [armchair (n,n) or near-armchair (n,n-1) direction] are at the inner position, i.e., closest to the 1/d line. At the outermost positions are the tubes with smallest chiral angle, i.e., zigzag (n,0) or near-zigzag (n,1) tubes. Starting there with chirality (n_1,n_2) , the neighboring tubes in the same branch (*laola*) are given by

$$(n'_1, n'_2) = (n_1 - 1, n_2 + 2) \tag{4}$$

with $n'_1 > n'_2$. For example, the (12,1) *laola* contains the following tubes: (12,1), (11,3), (10,5), (9,7); compare also Fig. 2. The tubes belonging to the same branch can also be specified by $2n_1+n_2$ being constant.⁸ Our assignment makes use of these branches, requiring a good agreement between the patterns of the branches in theory and experiment. In particular, the number of tubes within a given branch is unambiguously determined by the construction of a nanotube from a graphite sheet.¹

Figure 3 shows the best match between our experimental and theoretical Kataura plot obtained by the above method. The assignment of our data points to the chiralities (n_1, n_2) directly follows from this plot and is indicated for the first tube of each branch. We assign all of our data to the second transition of semiconducting tubes, E_{22}^S , and to the first transition of metallic tubes, E_{11}^M . For semiconducting tubes, we observe both the upper (open circles) and lower branches (full circles), whereas only the lower branches of metallic tubes are seen in the experiment. Because of the systematics of the Kataura plot, tubes with similar diameter and chiral angle but from different branches, such as the metallic (13,1) and the semiconducting (14,1) tube, cannot be easily confused.

The key point of the assignment by pattern recognition and pattern matching is that it greatly reduces the possible choices for an assignment. Take, for instance, the point at $1/\omega_{\text{RBM}}=0.33\times10^{-2}$ cm and $E_{22}=1.78$ eV that is assigned to the (9,1) tube in Fig. 3. We cannot assign this particular RBM to the (10,0) tube, because the (10,0) is at the wrong side of the 1/d line. We also see from the patterns that the TABLE I. Summary of all observed RBM frequencies and transition energies of semiconducting tubes and their assignment. The tubes are grouped according to the branches (*laola*) in the Kataura plot. $\omega_{\text{RBM}}^{\text{emp}}$ and E_{ii}^{emp} give the empirical values from Eq. (1) with c_1 =215 cm⁻¹ nm, c_2 =18 cm⁻¹, and from Eq. (5), respectively. The index $\nu = (n_1 - n_2) \mod 3 = \pm 1$ indicates the two types of semiconducting tubes ($\nu = -1$ corresponds to $\nu = 2$, as sometimes used in the literature). The diameters are calculated with a_0 =2.461 Å. The nanotube sample contained SDS as surfactant for excitation energies above 1.99 eV; below SDBS was used as surfactant. The experimental error of the transition energies is between 3 meV (three digits) and 30 meV (two digits). In the last column we give the Raman susceptibility in arbitrary units, obtained by normalizing the maximum RBM peak area to integration time, laser power, relative spectrometer response, and ω^4 . The intensity changes due to different surfactants are taken into account; see Secs. VIII and IX. The asterisks indicate susceptibility values with large experimental errors due to weak signal or incomplete resonance profiles.

						F	emp	r emp		
ν	laola	n_1	n_2	<i>d</i> (Å)	$\omega_{\rm RBM}({\rm cm}^{-1})$	(eV)	(cm^{-1})	(eV)	θ	Suscept.
-1	(12.1)	12	1	9.82	236.4	1 551	237	1 54	4.0	4 1
1	(12,1)	11	3	10.00	232.6	1.570	233	1.55	11.7	2.0
		10	5	10.36	226.1	1.578	225	1.56	19.1	2.3
		9	7	10.88	216.0	1.564	215	1.55	25.9	1.3
-1	(11,0)	11	0	8.62	266.7	1.657	267	1.68	0.0	1.7
		10	2	8.72	264.6	1.690	264	1.69	8.9	2.3
		9	4	9.03	257.5	1.72	256	1.71	17.5	2.5
		8	6	9.53	246.4	1.73	243	1.72	25.3	1.4
-1	(9,1)	9	1	7.47	306.2	1.78	305	1.83	5.2	9.1
		8	3	7.72	297.5	1.857	296	1.88	15.3	35.8
		7	5	8.18	283.3	1.915	281	1.92	24.5	18.3
-1	(8,0)	8	0	6.27	352.2	1.99	361	1.97	0.0	0.1
		7	2	6.41			353	2.03	12.2	
		6	4	6.83			333	2.15	23.4	
+1	(14,1)	14	1	11.38	205.8	1.646	207	1.66	3.4	0.3
		13	3	11.54	203.3	1.610	204	1.62	10.2	0.6
		12	5	11.85	198.5	1.554	199	1.56	16.6	0.1
		11	7	12.31			192	1.47	22.7	
		10	9	12.90			185	1.38	28.3	
+1	(13,0)	13	0	10.18	230.8	1.84	229	1.85	0.0	0.2^{*}
		12	2	10.27	228.1	1.82	227	1.82	7.6	12.2^{*}
		11	4	10.54	221.8	1.76	222	1.74	14.9	0.1^{*}
		10	6	10.97			214	1.64	21.8	
		9	8	11.54	204.0	1.535	204	1.52	28.1	0.5
+1	(11,1)	11	1	9.03	256.0	2.031	256	2.06	4.3	9.8
		10	3	9.24	252.1	1.945	251	1.98	12.7	3.6
		9	5	9.63			241	1.84	20.6	
		8	7	10.18	230.4	1.710	229	1.69	27.8	0.4
+1	(10,0)	10	0	7.83	291.4	2.38	292	2.35	0.0	
		9	2	7.95			288	2.28	9.8	
		8	4	8.29	280.9	2.10	277	2.11	19.1	0.3
		7	6	8.83	264.2	1.909	261	1.91	27.5	2.6
+1	(8,1)	8	1	6.69			339	2.69	5.8	
		7	3	6.96			327	2.48	17.0	
		6	5	7.47	308.6	2.20	305	2.18	27.0	

(9,1) point has to be assigned to the outermost tube in a branch. This leaves us with two or three alternative assignments, where we shift the entire experimental and theoretical plot with respect to each other. We show in the next paragraph that such an attempt leads to contradictions between theory and experiment. We also discuss the possibility of

assigning some of our data to different sets of transitions like E_{11}^S instead of E_{22}^S .

(Im)possible alternative assignments

We first consider assigning our $(\omega_{\text{RBM}}, E_{ii})$ pairs to a different branch, keeping the overall assignment to the second

TABLE II. Summary of all observed RBM frequencies and transition energies of metallic tubes and their assignment. For metallic tubes, $\nu=0$. Except for armchair tubes, each metallic tube has two close-by transition energies (Ref. 45) of which always the lower one was observed in the experiment.

ν	laola	n_1	<i>n</i> ₂	d (Å)	$\omega_{\rm RBM}~({\rm cm}^{-1})$	E_{ii} (eV) a	$\omega_{\rm RBM}^{\rm emp}~({\rm cm}^{-1})$	$E_{ii}^{\rm emp}$ (eV)	θ	Suscept.
0	(16,1)	16	1	12.94	182.0	1.81	184	1.81	3.0	0.5
		15	3	13.08	179.0	1.83	182	1.81	8.9	1.8
		14	5	13.36	174.5	1.83	179	1.81	14.7	1.9
0	(15,0)	15	0	11.75	200.4	1.908	201	1.93	0.0	0.7
		14	2	11.83	196.3	1.934	200	1.94	6.6	3.6
		13	4	12.06	193.5	1.944	196	1.94	13.0	2.5
		12	6	12.44	189.4	1.948	191	1.93	19.1	1.9
		11	8	12.94	183.2	1.936	184	1.92	24.8	1.9
		10	10	13.57	175.7	1.889	176	1.88	30.0	0.9
0	(13,1)	13	1	10.60	220.3	2.057	221	2.07	3.7	1.5
		12	3	10.77	217.4	2.075	217	2.07	10.9	2.6
		11	5	11.11	212.4	2.084	211	2.08	17.8	1.7
		10	7	11.59	204.0	2.067	203	2.07	24.2	0.9
		9	9	12.21	195.3	2.02	194	2.04	30.0	0.5
0	(12,0)	12	0	9.40	244.9	2.18	247	2.21	0.0	
		11	2	9.50			244	2.22	8.2	
		10	4	9.78			238	2.24	16.1	
		9	6	10.24			228	2.25	23.4	
		8	8	10.85			216	2.23	30.0	
0	(10,1)	10	1	8.25	276.3	2.38	278	2.35	4.7	
		9	3	8.47	272.7	2.43	272	2.40	13.9	
		8	5	8.90	262.7	2.47	259	2.45	22.4	
		7	7	9.50	247.8	2.45	244	2.46	30.0	
0	(9,0)	9	0	7.05			323	2.47	0.0	
		8	2	7.18	315.5	2.52	317	2.53	10.9	
		7	4	7.55	305.4	2.63	302	2.65	21.1	
		6	6	8.14			282	2.71	30.0	

transition in semiconducting and the first transition in metallic tubes. Figure 4(a) shows the combined experimental and theoretical Kataura plot when shifting the experimental data to the left or "up" by one branch. The upshift results in experimental branches where the number of RBMs is larger than the number of tubes in the branch [circle in Fig. 4(a)]. This assignment is therefore incorrect.

Figure 4(b) is the plot for shifting the experimental data to the right or "down." Some branches then have less RBMs than tubes. This is quite possible if we have not detected all nanotubes in the diameter range. The assignment suggested in Fig. 4(b), however, strongly violates the patterns in the nanotube diameter distribution as we explain now. The diameter patterns are best seen for the outermost members of each branch in Fig. 3: because every second branch starts with a zigzag tube, the distance between the two outermost points of the branches alternates between extremely close in $1/\omega_{\text{RBM}}$ and slightly further apart when going from one branch to the next. This pattern is found in the experimental data as well, compare, for instance, the (9,1) and (12,1) branches in Fig. 3 (two outermost points more separated along the *x* axis) to the (11,0) branch (two outermost points close together). The important argument here is again the *pattern*, not the agreement or disagreement on an absolute $1/\omega_{\text{RBM}}$ scale. We can therefore exclude the assignment of Fig. 4(b) as well. A shift of the branches by more than one branch up or down increases the disagreement between theory and experiment.

One might also think of assigning the experimental data to different transitions E_{ii} , for example, shifting the experimental data down such that the measured RBM resonances correspond to the first transition of semiconducting tubes E_{11}^S instead of the second transition E_{22}^S . The data assigned to metallic tubes in Fig. 3 then correspond either to E_{22}^S or to E_{11}^M (as before). Likewise, all data might be shifted up such that the E_{22}^S data correspond to the metallic transitions E_{11}^M and so forth. Although these alternative assignments are more of academic interest, since we know the E_{22}^S transitions



FIG. 3. (Color online) Experimental (large open and closed circles, left and bottom axes) and theoretical (small gray circles, right and top axes) Kataura plot. The second transitions of semiconducting tubes E_{22}^S and the first transitions E_{11}^M of metallic tubes are shown. The solid lines give the approximate 1/d dependence of the transition energies. The dashed lines indicate the "V"-shaped branches, where the chirality of a tube is related to its left neighbor (n_1,n_2) by $(n'_1,n'_2)=(n_1-1,n_2+2)$. In the experimental data, the assignment is given for the first tube in each branch, where upright numbers indicate semiconducting tubes are divided into two families with $\nu = (n_1 - n_2) \mod 3 = -1$ (full circles, lower branches) and with $\nu = +1$ (open circles, upper branches).

from photoluminescence,⁴ we want to discuss these "exotic" assignments briefly. We show that assigning our measured energies to other transitions than E_{22}^S and E_{11}^M systematically violates the Kataura-plot patterns and therefore result in incorrect assignments. It is an intriguing exercise highlighting very nicely the systematics in the Kataura plot and the pattern recognition idea.

Let us consider assigning the experimental E_{22}^{S} data in Fig. 3 to the metallic E_{11}^{M} resonance. The upper and lower branches of metallic transitions in the Kataura plot belong to the same chiralities. Thus the RBM frequencies in the upper and lower branches must be the same. This is in contrast with experiment, where the upper branches (open circles in Fig. 3) begin and end at larger diameter than the corresponding branches on the opposite side of the 1/d line.

A downshift of the E_{22}^S data to the E_{11}^S transition is also impossible. When switching from a transition E_{ii}^S to the next higher or lower transition, the family dependence is reversed. For E_{22}^S the +1 tubes are above the 1/d line (see Fig. 3); for E_{11}^S the $\nu = +1$ tubes are below the 1/d line, vice versa for the $\nu = -1$ tubes.^{1,45} The two families start and end at different relative diameters for a given V-like curve. Changing the family dependence in the theoretical points by going from E_{22}^S to E_{11}^S completely disturbs the patterns. In Fig. 5 we show such an attempt in detail. The former-assigned E_{22}^S



FIG. 4. (Color online) Kataura plot showing two assignments that violate the pattern system and are therefore incorrect. (a) The experimental data were shifted "up" (to the upper left corner) when compared to Fig. 3. Only two experimental branches are shown for clarity. The circle highlights the Kataura branch where this assignment produces five experimental RBMs for a branch that contains only four nanotubes. (b) same as (a), but for the shift down. The vertical lines highlight regions where the 1/d patterns of the RBM are violated.

data are shifted down to the E_{11}^S transitions. We stretched and displaced the Kataura plot to get the best match for the upper parts of the V-shaped curves, which now correspond to ν =-1 tubes (open circles). Obviously, the lower, ν =+1, branches strongly violate the Kataura patterns. They are shifted to larger diameters with respect to the theoretical data. The situation gets even worse if we take the metallic tubes into account as well. Assigning them, e.g., to E_{22}^S is impossible, because this results in nanotubes with the same chirality, but two different RBM frequencies.

We systematically considered other "exotic" assignments as well, e.g., the idea that certain data points in an experimental V-like curve are resonances coming from a different optical transition than the other points, say E_{22}^S transitions are mixed with E_{11}^S transitions in one and the same V-like curve in Fig. 3. All these ideas can be excluded in a similar way as discussed for some selected alternative assignments in the preceding paragraphs. The assignment in Fig. 3 is the only one that matches the systematics in the Kataura plot and obeys the 1/d patterns of the RBM frequencies. We summarize all measured RBM frequencies together with the assignment in Tables I and II.

Our Raman based assignment agrees with Bachilo's *et al.*⁴ suggestions from photoluminescence. They used a similar idea of pattern matching to correlate the theoretical transition



FIG. 5. (Color online) Kataura plot showing a trial assignment where the experimental data are shifted down to the E_{11}^S transitions. This assignment is incorrect for several reasons; see text. While the experimental upper branches (open circles) match quite well the pattern of the theoretical data, the lower branches disagree. The data assigned to the metallic tubes (large dark circles) cannot be assigned to the second semiconducting transitions E_{22}^S , because they should be at exactly the same RBM frequencies (diameters) as the upper E_{11}^S branches (open circles), which they are not.

energies with experiment.^{4,41} The luminescence-based assignment was ambiguous; it needed an additional anchor element. There are two reasons why the ($\omega_{\text{RBM}}, E_{ii}$) pairs found by Raman scattering restrict the possible assignment more strongly than the (E_{11}, E_{22}) pairs from luminescence: First, Raman scattering detects more nanotubes than photoluminescence, in particular, the metallic tubes and the tubes with small chiral angles at the end of the Kataura branches (zigzag and close-to-zigzag tubes). Second, ω_{RBM} is to good approximation independent of the chiral angle, whereas the E_{ii} depend on diameter and chiral angle. This reduces the degrees of freedom for the ($\omega_{\text{RBM}}, E_{ii}$) pattern matching when compared to the (E_{11}, E_{22}) matching and makes Raman scattering less ambiguous than photoluminescence.

In summary, we assigned experimental RBM frequencies (together with E_{ii}) to particular nanotubes indices (n_1, n_2) . Based on this assignment, we correlate the RBM frequencies with tube diameters in Sec. VII. Our assignment is independent of empirical parameters. The measured optical transition energies are excitonic energies, as known from recent experiments.15,16 As the assignment procedure does not rely on absolute energies when comparing with the theoretical Kataura plot, the results are not affected by the strength of exciton binding in carbon nanotubes. In fact, our assignment is based on two patterns: The systematics in the distributions of tube diameters with n_1 and n_2 , which comes from the $c = n_1 a_1 + n_2 a_2$ construction of a tube, and the family behavior of the nanotube transition energies.^{1,45} As long as these two very general concepts in nanotube physics remain valid, our Raman based assignment is unique.

VI. TRANSITION ENERGIES OF SEMICONDUCTING AND METALLIC TUBES

In this section we provide empirical fits to the experimental transition energies E_{22}^S and E_{11}^M in order to apply these



FIG. 6. (Color online) Experimental transition energies (open symbols) and empirical values from Eqs. (5) and (6) (closed symbols). For the metallic branches, the inner (armchair) tube is indicated.

expressions to chiralities not observed in the experiment. We start with the 1/d relation for the band gap, $E_{ii}=2i\gamma_0 a_{C-C}/d$,^{1,46} expanding it in 1/d. We add a chiralangle dependent term to model the branches of the Kataura plot, which is larger for smaller diameters.^{45,47} For the E_{22}^S transitions of semiconducting tubes,

$$E_{22}^{S} = \gamma_0 \left(\frac{4a_{\text{C-C}}}{d} + \gamma_1 \frac{a_{\text{C-C}}^2}{d^2} \right) + \nu \gamma_2 \cos(3\theta) \frac{a_{\text{C-C}}^2}{d^2}, \quad (5)$$

with the parameters γ_0 , γ_1 , and γ_2 . a_{C-C} is the length of the carbon-carbon bonds $(a_{C-C}=a_0/\sqrt{3})$, and $\nu=(n_1-n_2) \mod 3$ is the family index taking the values ± 1 in semiconducting tubes and $\nu=0$ in metallic tubes. θ is the chiral angle of the (n_1, n_2) tube, being zero in zigzag tubes.¹ From the fit to our data we obtain $\gamma_0=3.53$ eV, $\gamma_1=-4.32$, and $\gamma_2=8.81$ eV. Analogously, we approximate the transition energies in metallic tubes by

$$E_{11}^{M} = \gamma_0 \left(\frac{6a_{\text{C-C}}}{d} + \gamma_1 \frac{a_{\text{C-C}}^2}{d^2} \right) - \gamma_2 \cos(3\theta) \frac{a_{\text{C-C}}^2}{d^2}, \qquad (6)$$

and find γ_0 =3.60 eV, γ_1 =-9.65, and γ_2 =11.69 eV. The empirically determined energies are shown as a function of diameter in Fig. 6, where *d* is given by (n_1, n_2) [Eq. (2)]. Because the electronic properties change dramatically for small-diameter tubes,^{48,49} the empirical data given here are valid only for tubes with diameters $d \ge 6$ Å. Our empirical extrapolation fits well with the experimental E_{22}^S data obtained by Doorn *et al.*¹⁷ for the tubes outside the range of our experiments. All empirical transition energies are listed in the supplementary material, Ref. 50.

The γ_0 obtained from Eqs. (5) and (6) are quite close to the corresponding parameter in graphite (3.2 eV, Ref. 51) and much larger than assumed for carbon nanotubes in the past (2.5–2.75 eV, Refs. 27 and 52). From our fits it seems that γ_1 scales with the square of $i (E_{11}=E_{11}^S, E_{22}=E_{22}^S, E_{33}=E_{11}^M$; see Refs. 1 and 46), whereas the chirality-dependent correction shows only a linear scaling. These corrections reflect a mixture of trigonal warping of the graphene band structure,⁴⁵ curvature effects,^{21,53} and exciton effects.^{42,43} Very recently, experimental results on the exciton binding energies in carbon nanotubes were published.^{15,16} Although Maultzsch et al.¹⁶ reported a family dependence of the exciton binding energies and also a dependence on the size of the nanotube band gap, it is difficult to quantify these effects from the data at hand. Perebeinos et al.43 suggested a scaling of the exciton binding energy with the effective mass of the electron and the hole as $E_b \propto m^{\alpha-1}$, where $\alpha = 1.4$ was found from tightbinding calculations. The effective mass in turn depends on the family of a tube and its diameter and chiral angle. Nevertheless, for the time being we prefer to understand Eqs. (5) and (6) as empirical functions instead of giving the parameters and dependences a strict physical meaning in terms of curvature and exciton effects. The two relations fit the experimental data very well; see Fig. 6. It would be interesting to obtain Raman data for the first optical transition energy to see whether the proposed scaling for γ_1 and γ_2 applies to this transition as well.

Strano and co-workers^{18,54} used a similar expression to fit the observed transition energies in semiconducting and metallic tubes. Our results for semiconducting tubes are in good agreement with the empirical values in Refs. 18 and 54. For metallic tubes, in contrast, we find large deviations between our experimental data and the empirical data in Ref. 18. In particular, the Raman resonances of some metallic tubes were assigned to the second metallic transitions in Ref. 18, whereas from our data it is obvious that only the *first* metallic transitions are observed. For example, the resonance of the (7,7) armchair tube (see Fig. 6), i.e., at the inner position of a "V"-shaped branch, is in Ref. 18 assigned to the second resonance of the (12,0) zigzag tube. Therefore the empirical expressions given by Strano et al.18 underestimate the transition energies of metallic tubes.

In Ref. 9 a detailed comparison between the experimental transition energies with tight-binding results can be found. The authors present diameter and chirality-dependent corrections involving eight fitting parameters for each set of transitions.

VII. RELATION BETWEEN ω_{RBM} AND DIAMETER

In contrast to previous attempts to obtain (n_1, n_2) from the Raman spectrum of a tube27,29 we first assigned an RBM frequency to a nanotube. We used the fact that the RBM frequency is approximately linear with the inverse tube diameter. We did, however, not include Eq. (1) explicitly, in particular, no values c_1 and c_2 were given. From this assignment we now calculate the tube diameter and fit c_1 and c_2 from the ω_{RBM} vs diameter plot. The key difference to other work is that a particular Raman line is always assigned to the same nanotube within our approach. Using, e.g., the diameters reported by Kürti et al.²⁴ from first-principles calculations instead of the geometrical expression in Eq. (2) we find slightly different numbers for c_1 and c_2 . The assignment in Tables I and II, however, remains the same. For an assignment it is usually better to work with the tables instead of Eq. (1) as we discuss in Sec. X.



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FIG. 7. (Color online) Linear fit of the observed RBM frequencies as a function of inverse tube diameter 1/d. The diameter of the assigned nanotubes is calculated from Eq. (2) with $a_0=2.461$ Å.

and $c_2 = 18 \text{ cm}^{-1}$. With $a_{C-C} = a_0 / \sqrt{3} = 1.44 \text{ Å}$, also used in the literature, $c_1 = 218 \text{ cm}^{-1} \text{ nm}$ and $c_2 = 18 \text{ cm}^{-1}$. The coefficients are thus very sensitive to how the tube diameter is determined. Therefore they provide an estimate of the RBM frequency for a given diameter [Eq. (1)], but should not be used to compare (or even assign) an experimental RBM frequency to a nanotube diameter with high accuracy.

Deviations from the linear dependence of the RBM frequency on the inverse diameter have been predicted for small-diameter tubes by Kürti et al.24 from first-principles calculations. In Raman experiments, based on the assignment of Ref. 4, Jorio et al.9 observed deviations of a few wave numbers, depending slightly on the chiral angle. Here we show explicitly that the behavior of the experimental RBM agrees very well with the calculations in Ref. 24.

Figure 8 shows the difference $\Delta \omega_{\text{RBM}}$ between the experimental ω_{RBM} and the empirical values calculated from Eq. (1) with $c_1=215$ cm⁻¹ nm and $c_2=18$ cm⁻¹ (full circles). In general, the deviations from the linear fit increase for smaller diameters, in agreement with the predictions. They vary between +4 and -2 cm^{-1} , depending on the chiral angle. For tubes with $d \leq 10$ Å, $\Delta \omega_{\text{RBM}}$ has a large and positive value for (near-)armchair tubes and decreases to negative values for (near-)zigzag tubes.

Kürti et al.24 showed that isolated armchair tubes follow the linear relation with the smallest deviations, whereas zigzag tubes have the largest (negative) deviation. If we assume the line connecting the armchair tubes in Fig. 8(a) to be the $\Delta \omega_{\rm RBM} = 0$ line,⁵⁵ we observe the same trend of increasing deviation towards zigzag tubes. This agrees with the prediction that zigzag tubes show the strongest rehybridization effects²¹ and the largest increase in bond length,²⁴ both effects resulting in a weakening of the RBM frequency.

To compare with the theoretical data of Ref. 24 quantitatively, we performed a linear fit to the *ab initio* values $\omega_{\text{RBM}}^{\text{DFT}}$ and analyzed the differences between $\omega_{\text{RBM}}^{\text{DFT}}$ and this linear fit (open circles in Fig. 8). We find a very good quantitative agreement between experiment and theory, although the calculations were performed for isolated tubes in vacuum. This confirms that the deviations from the linear relation are mostly due to changes in the strength of the bonds (rehybridization and bond lengths).

VIII. RBM INTENSITIES

In Fig. 7 we show a linear fit to our data points according to Eq. (1). Using $a_0 = 2.461$ Å, we obtain $c_1 = 215$ cm⁻¹ nm

The Raman resonance profile given by Eq. (3) accounts for the position of the resonance maximum, which we dis-



FIG. 8. (Color online) Difference between experimental RBM frequencies and calculated RBM frequencies from Eq. (1) with $c_1 = 215 \text{ cm}^{-1} \text{ nm}$ and $c_2 = 18 \text{ cm}^{-1}$ (full circles). The lines connect tubes of the same branch, labeled by the first member according to the Kataura plot and Tables I and II. (a), (b), and (c) show the tubes with $\nu=0$, $\nu=+1$, and $\nu=-1$, respectively. The chiral angle within each branch decreases with decreasing diameter. Open circles show the difference between $\omega_{\text{RBM}}^{\text{DFT}}$ from first-principles calculations (Ref. 24) and ω_{RBM} from a linear fit to these theoretical data. In (a) the armchair tubes are indicated.

cussed so far. In this section, we evaluate the relative strength of the Raman signal to obtain information on the matrix elements \mathcal{M} . The matrix elements \mathcal{M} consist of the electron-photon coupling, $\mathcal{M}_{e\text{-}r}$, and the electron-phonon coupling, $\mathcal{M}_{e\text{-}ph}$, and $|\mathcal{M}|^2 = |\mathcal{M}_{e\text{-}r}\mathcal{M}_{e\text{-}ph}\mathcal{M}_{e\text{-}r}|^2$. The constant c contains the remaining factors such as response of the spectrometer and ω^4 dependence of the Raman cross section (taken into account by normalization to the nonresonant Raman signal of BaF₂ and CaF₂), laser power, integration time, scattering volume, and concentration of the nanotube solution. We do not make any assumptions on the diameter and chirality distribution in our sample, thus showing the bare Raman intensities. The diameter distribution can be determined by electron miscroscopy⁵⁶ or electron diffraction.⁵⁷ As we show below, the relative abundance of particular chiralities cannot be determined by the bare Raman or luminescence intensities.

In Fig. 9 we show part of the experimental Kataura plot, where the area of the circles indicates the strength of the Raman signal. We observe two trends: first, the Raman cross section increases for smaller diameter; second, it is in general much larger for the lower branches (ν =-1 for E_{22}^{S}) than for



FIG. 9. (Color online) Part of the experimental Kataura plot, where the intensity of the Raman signal is given by the area of the circles. Grey and black symbols indicate semiconducting and metallic tubes, respectively. The smallest circles account for all values below 0.5 in Table I. The crosses indicate tubes with large uncertainty in the Raman intensity; see also Table I. In addition to the normalization procedure described in the text, the intensity of the (11,1) tube is divided by 3.4 and the intensity of the (13,1) branch is multiplied by 3. This accounts for the changes in the Raman signal strength due to a different surfactant for the sample used above E_l =1.99 eV; see Sec. IX.

the upper branches. The upper branches of metallic tubes were not observed at all. Both the diameter dependence and the $\nu = \pm 1$ dependence were predicted by first-principles calculations of the electron-phonon coupling matrix elements \mathcal{M}_{e-vh} ,²² see also Ref. 58.

The electron-phonon coupling for the RBM becomes stronger for smaller-diameter tubes, because the same radial displacement results in a larger change of the carbon-carbon bonds in smaller tubes. The dependence on $\nu = \pm 1$ can be understood within the zone-folding picture. The index ν $=\pm 1$ indicates from which side of the *K* point in the graphene Brillouin zone the electronic states are derived. In graphene, the coupling between electrons close to the *K* point and phonons analogous to the RBM is larger between the *K* and *M* points than in the *K*- Γ direction.²² Similar results from Raman scattering were reported by Doorn *et al.*¹⁷ and Jorio *et al.*;⁹ calculations within an empirical tightbinding description give the same dependence on $\nu = \pm 1$.^{58,59}

According to the *ab initio* calculation by Machón *et al.*,²² we expect the opposite family behavior for Raman scattering in resonance with the *first* transition energy of semiconducting tubes. For this resonance, the Raman susceptibility of the ν =+1 nanotubes should be larger than the susceptibility of the ν =-1 nanotubes. Once again, this can be understood in the zone-folding approach, because the first and second optical transition in a nanotube originate from opposite sides of the *K* point.

Within each branch, the Raman intensity depends systematically on the chiral angle. It is small for tubes close to the armchair direction (inner position) and first increases with decreasing chiral angle. Close to the zigzag direction (outer positions) the intensity is small again. This is explained by the chiral-angle dependence of both the electron-phonon coupling and the strength of the optical transitions.^{7,36} The electron-phonon coupling is stronger for zigzag tubes than for armchair tubes, explaining the weaker signal for the close-to-armchair tubes.²² The luminescence, on the other hand, was observed to decrease for close-to-zigzag tubes,⁴ in particular for the ν =+1 branches.³⁶ Although we do not know directly the chirality dependence of absorption strength into the second semiconducting transitions E_{22}^{S} , we can assume that it has an opposite dependence on chiral angle than the electron-phonon coupling, explaining the decrease of the resonant RBM signal towards the zigzag direction.

In the last column of Tables I and II we show the intensity of the measured RBM signal normalized to the Raman signal of CaF_2 and BaF_2 and divided by the Bose-Einstein occupation number. These values are proportional to the Raman susceptibility.

IX. DEPENDENCE ON THE TYPE OF SURFACTANT

In the previous sections we assumed the RBM frequency and the optical transition energies to reflect only the intrinsic properties of carbon nanotubes. Now we address the dependence of their properties on the surfactant (SDS or SDBS), i.e., the environment of the tube. The surfactant has a small influence on the position of the experimental data points in the Kataura plot both along the frequency (diameter) and the excitation energy axes. Besides the fundamental interest in the interaction between a nanotube and its surrounding, environment-related effects can affect a nanotube assignment based on a *single* Raman spectrum and the RBM frequency alone (see Sec. X). The pattern-based assignment, however, is unaffected by the shifts, because they are small and do not fundamentally change the experimental patterns.

To analyze the surfactant-induced changes in the Raman spectra, we recorded resonance profiles for both surfactants with excitation energies between 1.85 and 2.2 eV; see Fig. 10. In this region, the laser energies are in resonance with both metallic and semiconducting tubes. We observe changes of (i) the transition energies, (ii) the Raman intensities, and (iii) the RBM frequencies.

For semiconducting tubes [Figs. 10(a) and 10(b)], the transition energies shift by \approx 5–10 meV to larger values in the SDS sample (open dots). In addition, the RBM signal of semiconducting tubes is stronger in the SDS sample than in the SDBS sample (closed dots). The behavior of metallic tubes is opposite: their RBM intensity is larger in the SDBS sample. The shift of transition energies is, if detectable, of similar magnitude as in semiconducting tubes but in opposite direction, i.e., the transition energies of metallic tubes are slightly larger with SDBS as surfactant, see also Table III. These changes are, however, small, and in particular for several tubes of the metallic (15,0) branch within the experimental error.

In Figs. 11 and 12 we compare the RBM spectra for both surfactants at the same laser energy in the region of semiconducting and metallic tubes, respectively. The RBM frequency of semiconducting tubes is the same in both surfactants within experimental error (gray black curves in Fig. 11). The relative RBM intensities, in particular of the (8,3) and the



FIG. 10. (Color online) Resonance profiles of the RBM for surfactants SDS (open red dots) and SDBS (filled black dots). The chiral indices, the chiral angle θ , and the family ν are given. Semiconducting tubes, (a) and (b), show a small upshift in the position of resonance maximum for SDS. In metallic tubes, (c) and (d), the shift of the transition energies is in opposite direction. The RBM intensity of metallic tubes is stronger in the SDBS sample, while the intensity of semiconducting tubes is stronger in the SDBS sample. Since the concentration of nanotubes in both solutions is not known exactly, we cannot quantify the absolute intensities. Comparing the relative intensities between the two surfactants, they change in opposite directions for metallic and semiconducting tubes.

(7,5) tube, are different in these spectra, reflecting the small shift of transition energy and hence of the resonance condition. The original intensity ratio in the SDS sample at E_l =1.916 eV is recovered if the SDBS sample is excited at a slightly lower energy (E_l =1.908 eV, dashed curve). This shift in laser energy compensates for the shift in the optical transition energy of semiconducting tubes. In metallic tubes we observe an upshift of the RBM frequencies in the SDS sample by about 2 cm⁻¹; see Fig. 12.

The dependence of the RBM frequency and intensity in metallic and semiconducting tubes on the type of surfactant agrees with the observation by Strano *et al.*⁶⁰ of selective functionalization of metallic tubes. They found a decrease of the absorption strength for the metallic E_{11}^M transitions, resulting from functionalization with tetrafluoroborate salt and formation of covalent bonds. Simultaneously, the RBM shifted to larger frequency. We can thus interpret our results as due to an interaction between the surfactant and the nanotube, which is stronger for SDS than for SDBS. Although it is unlikely that a covalent bond forms as in the case of Ref. 60, an electron transfer from the metallic tubes to the surfactant might occur. The Raman intensity decreases in SDS as the resonant absorption becomes weaker, simultaneously the interaction leads to a larger RBM frequency. From our data we

	SDBS	5	SDS								
Tube	$\omega_{\rm RBM}~({\rm cm}^{-1})$	E_{ii} (eV)	$\omega_{\rm RBM}~({\rm cm}^{-1})$	E_{ii} (eV)	$\Delta \omega ~({\rm cm}^{-1})$	$\Delta E(\text{meV})$					
Metallic nanotubes											
(15,0)	200	1.91	203	1.91	-3	0 ± 20					
(14,2)	196	1.93	199	1.93	-3	0 ± 10					
(13,4)	193	1.94	196	1.93	-3	10 ± 10					
(12,6)	189.4	1.948	191.1	1.938	-1.7	10±6					
(11,8)	183.2	1.936	184.1	1.906	-0.9	30±8					
Semiconducting nanotubes											
(8,3)	297.5	1.857	297.5	1.877	0.0	-20 ± 13					
(7,5)	283.3	1.915	283.2	1.919	0.1	-4 ± 4					
(7,6)	264.2	1.909	263.6	1.917	0.6	-8 ± 6					
(10,3)	252.1	1.945	252.1	1.953	0.0	-8 ± 6					

TABLE III. Comparison of transition energies and RBM frequencies for different surfactants (SDS and SDBS). All transition energies are obtained from resonance profiles. The experimental errors for the first three tubes of the (15,0) branch are larger than for the majority of our data.

cannot detect such a difference in the interaction for semiconducting tubes, as the RBM is constant when changing the surfactant.

The small shift in transition energies might be to first approximation assigned to a change in the dielectric environment. It is for several tubes within the range of experimental error. We have no explanation yet for the shift in opposite direction for metallic and semiconducting tubes.

Izard *et al.*⁶¹ studied the development of RBM spectra from bundled tubes to bundles wrapped by SDS and to individual tubes in SDS. They also observed an upshift of the RBM due to wrapping by SDS which they assigned to pressure induced by the surfactant. The metallic tubes appear to be more sensitive to the surfactant, as the RBM shift is in general larger than for semiconducting tubes, in agreement with our results. Izard *et al.*⁶¹ observed changes in the relative RBM intensities as well, which they ascribed to a selective exfoliation process. From our data, we rather suggest a small change in resonance condition.



FIG. 11. (Color online) RBM spectra of nanotubes dispersed in D_2O using SDBS (black) and SDS (gray) as surfactants at excitation energy 1.916 eV (solid lines) and 1.908 eV (dashed lines). The spectra are normalized to the RBM amplitude of the (7,5) tube.

Our assignment of Sec. V is not affected by the surfactant-induced variation in the transition energies and RBM frequencies. Figure 13 shows a small section of the Kataura plot with data from SDS (open dots) and from SDBS (closed dots). The differences in excitation energies and RBM frequencies are minor on the scale of the Kataura plot. The most important criteria for the assignment are the RBM frequency patterns and the number of tubes within a branch. Figure 13 shows that the small variations of the RBM do not change these systematics. In particular, the changes are too small to shift the data to a different branch.



FIG. 12. (Color online) Metallic part of the RBM spectrum. Gray: SDS sample; black: SDBS sample. Thin lines show the fit of the RBM peaks by Lorentzians. The peaks are shifted to higher frequencies in the SDS sample.



FIG. 13. (Color online) Section of the Kataura plot showing the transition energy vs inverse RBM frequency of nanotubes in two different surfactants: SDS (open dots) and SDBS (closed dots). Semiconducting tubes (gray) show a uniform shift of the transition energies. Metallic tubes (black) are shifted in energy and RBM frequency.

Therefore the assignment is valid for both types of surfactant.

X. HOW TO ASSIGN (n_1, n_2) IN A RAMAN EXPERIMENT

A great need for nanotube research is to identify the chirality of a tube before performing an experiment. Ideally, the method is nondestructive, does not require special equipment or substrates, works for semiconducting and metallic tubes, as well as individual tubes and bulk samples (nanotubes in solution or bundled tubes). It should also give reliable results regardless of the tube environment. We discussed possible ways for identifying carbon nanotubes in the introduction of this paper. Raman scattering meets many of the requirements for becoming one of the prime assignment methods for single-walled carbon nanotubes.

Most Raman-based assignments of individual and bundled tubes relied mainly on the $\omega_{\text{RBM}} \propto 1/d$ relationship using one value for c_1 and c_2 or the other; see the review in Ref. 1. In this paper we showed that the RBM frequency *alone* will never be sufficient for assigning the chirality, because it depends on the environment of the tubes. Although the changes in the RBM frequencies are small between different surfactants (Sec. IX) and also between bundled and surfactant-coated tubes,^{8,20,61} they are large enough to change an assignment that uses the RBM frequencies as the only input; see also Ref. 50. Therefore a Raman-based assignment of an individual tube, suspended or on a substrate, nanotubes in solution, nanotube bundles, and so forth, should always use the combined information of RBM frequency and excitation energy.

Once the full resonance Raman experiment has been performed and the assignment of ω_{RBM} to the chiral index has been found (Sec. V), the chiral indices of a sample containing tubes with similar diameters can be determined from one single Raman spectrum. Environment-related effects often can be taken into account by estimating the changes in the transition energies. In this section we explain the procedure and show how the RBM peaks in a given Raman spectrum can be assigned to (n_1, n_2) .



FIG. 14. (Color online) Experimental Kataura plot: transition energies vs RBM frequencies, from Tables I and II. The shaded regions correspond to the RBM peaks in Fig. 15.

For simplicity, we plot the experimental data of Fig. 3 (Tables I and II) now with the RBM frequency along the x axis; see Fig. 14. The procedure of the assignment is as follows:

1. Record a Raman spectrum at a given excitation energy E_l and determine the RBM frequencies ω_{RBM} (Fig. 15).

2. Identify groups of 3-5 close-by RBM peaks as indicated in Fig. 15 by the shaded areas. The members of these groups form a branch (*laola*) in the Kataura plot.

3. Find the excitation energy E_l in the experimental Kataura plot (horizontal line at 1.96 eV in Fig. 14).

4. Find along the *x* axis of the experimental Kataura plot the regions of observed RBM frequencies (shaded areas). The branches closest to E_l within these regions most likely contribute to the RBM spectrum.

5. Compare all RBM frequencies in detail with the experimental Kataura plot and the sequence of tubes in a



FIG. 15. (Color online) RBM spectrum at E_l =1.96 eV. The shaded regions indicate groups of metallic and semiconducting tubes; the chiral indices at the bottom give the first element of the corresponding *laola* in the Kataura plot (Fig. 14). The chiral indices at the top show the assignment of the strongest peaks.

branch to find the final assignment; see Fig. 15. Compare the number of tubes within this branch to how many of them are observed.

In the example given in Figs. 14 and 15, we identify the left and the right RBM groups as metallic and semiconducting tubes, respectively. Since the width of the resonance profiles is typically around 60 meV, we assume that we can observe tubes from a window of approximately 100-200meV width around the excitation energy. These areas are indicated in Fig. 14. For the metallic tubes, mainly the (15.0) branch contributes to the spectra. In the region of semiconducting tubes, the members of several branches are close to the excitation energy. We identify the peaks as resulting from tubes of the (11,1), (10,0), and (9,1) branches. In the final step, we assign the strongest peaks to the (11,8), (12,6), and (13,4) tube (metallic region) and to the (10,3), (7,6), (7,5), and (8,3) tube (semiconducting region), as indicated in Fig. 15. The remaining tubes of these branches, such as the (15,0)tube, are weaker shoulders of the strongest peaks and become evident when changing the laser wavelength. Others, like the members of the (10,0) branch, are outside the resonance window. Thus not all members of each branch are expected in the same single Raman spectrum; because of the chirality dependence of the Raman cross section some tubes might not be observed.

The most relevant piece of information is already obtained in the fourth step, i.e., by identifying the correct branches. Many properties are similar for tubes of the same branch. In contrast, they differ strongly for tubes of different branches even if the diameters or transition energies are almost the same. For example, the (7,5) and the (7,6) tube have very similar E_{ii} , but the (7,6) tube gives a much weaker RBM signal. This is due to the different strength of the electron-phonon coupling for $\nu = -1$ and $\nu = +1$ tubes,²² as explained in Sec. VIII.

In Raman measurements on a single, individual nanotube, the chiral index is found by the same method. For this type of samples the difficulty is to obtain an observable RBM signal, because of the narrow resonance window of the RBM. One, two or even three laser energies might be needed to find the resonance window of a particular tube. The laola groups—typical for samples with different chiralities—that allowed to identify branches, are absent in individual tubes. Nevertheless, following the procedure described above, the choice of possible chiralities can be narrowed to one or two tubes. If the ambiguity concerns two nanotubes from the same branch, a further refinement of the assignment is not necessary. Two neighboring tubes in the same branch are too similar in properties to easily distinguish between them. In turn, this implies that neither fundamental studies nor applications benefit much from narrowing down the choice. If, on the other hand, a single Raman spectrum is insufficient to distinguish between two branches, the ambiguity arose between two tubes of different family—metallic, $\nu = +1$ or ν -1 semiconducting. In this case the assignment should be verified by using a different excitation energy or by combining Raman scattering with a second assignment technique.

In Sec. IX we showed that changing the environment of the nanotubes did not affect the RBM frequencies of semiconducting tubes and only slightly those of metallic tubes.



FIG. 16. (Color online) RBM spectra with chiral-index assignment at several standard laser lines, 514, 752, and 785 nm. The peaks in the middle panel consist of two RBMs each which can only be resolved when changing the excitation energy. For the spectrum at 633 nm (1.96 eV) see Fig. 15.

This is consistent with the observation of only small RBM changes in bundles vs separated tubes and in tubes in several different surfactants.^{8,20,61} On the other hand, the transition energies E_{ii} appear to be more sensitive to the nanotube environment.^{8,20,61,62} Therefore the empirical values of E_{ii} given in Tables I and II are strictly valid only for nanotubes in SDS or SDBS and should be used with care for other types of samples. Ideally, one would perform the full resonance Raman experiment once for each tube environment, e.g., different surfactants, bundled tubes, individual tubes on a substrate, individual suspended tubes in air, etc. Some of these data have been reported in the literature, see, for instance, Refs. 8 and 20. In addition, photoluminescence data can be used for E_{ii} in different samples. The Raman-based assignment procedure, however, is always the same as described in this section. In particular, if entire branches are observed, the data presented in Tables I and II can be readily used, taking into account changes in the E_{ii} . As the RBM frequencies vary only slightly, the Raman-based assignment is much more stable against changes in the nanotube environment than an assignment based on the E_{ii} alone.

In standard Raman setups often just a few laser lines are available. To facilitate an assignment, we show in Fig. 16 the RBM spectra for the most common laser lines (514, 752, and 785 nm) together with the chiral indices. These spectra can be directly compared to Raman spectra taken on HiPCO tubes in solution with standard equipment and used for a simple assignment. Two tubes with very similar diameters are sometimes difficult to resolve from a single Raman spectrum, see the 752-nm spectrum in Fig. 16. Apparently only two tubes contribute. From the excitation-energy dependent measurements we know that each peak in the middle panel of Fig. 16 is, in fact, composed of two RBM lines.

XI. SUMMARY

In summary, we presented a chiral-index assignment for carbon nanotubes from resonant Raman scattering. The assignment is independent of any additional parameters, but it is based on pattern recognition. The two pieces of information that are required for this assignment are the frequency of the radial breathing mode and the energy of an optical transition (here E_{22}^S and E_{11}^M). They constitute an experimental Kataura plot where all chiral indices are systematically grouped into so-called branches with neighboring indices given by $(n'_1, n'_2) = (n_1 - 1, n_2 + 2)$. Because of these systematics, the assignment remains the same even if parameters in the calculation of E_{ii} or the diameter change or if the experimental values vary due to slightly different experimental conditions. (n_1, n_2) is assigned to experimental RBM frequencies and transition energies, irrespective of changes in the theoretical description. We consider all measured transition energies to be excitonic energies, as excitonic effects dominate the optical spectra in carbon nanotubes.

We derived the parameters $c_1=215\pm2$ cm⁻¹ nm and c_2 =18±2 cm⁻¹ from our assignment for the RBM-diameter re-

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lation. These values vary depending on the type of sample and on the details of the diameter calculation. The RBM intensities are in general stronger for $\nu = -1$ nanotubes than for $\nu = +1$ tubes for the E_{22}^S transitions. They decrease from their maximum around $\theta \approx 10^\circ - 15^\circ$ towards both the armchair and the zigzag direction. These results are in good agreement with *ab initio* calculations of the electron-phonon coupling.²² The intensities also depend on the type of surfactant in our samples with different behavior for metallic and semiconducting tubes. For metallic tubes, we observed a stronger interaction with SDS, and an upshift of the RBM frequencies.

Finally, we provided a description on how to find a chiralindex assignment from a single Raman spectrum. For samples with similar tube diameters in a similar environment, the experimental and empirical data given in Tables I and II and in Ref. 50 can be used for a straightforward assignment. Changes in the tube environment usually affect mainly the optical transition energies, which can be taken into account for an assignment. We stress that the RBM frequencies *alone* are insufficient for an assignment. It should always be based on the combined information of RBM frequency and excitation energy. Taking into account these two pieces of information results in a robust and reliable assignment based on Raman spectroscopy.

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